

M62015L/FP, M62016L/FP

Low Power 2 Output System Reset IC

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Description

The M62015 and M62016 are semiconductor integrated circuits whose optimum use is for the detection of the rise and fall in the power supply to a microcomputer system in order to reset or release the microcomputer system.

The M62015 and M62016 carry out voltage detection in two steps and have two output pins. As Bi-CMOS process and low power dissipating circuits are employed, they output optimum signals through each output pin to a system that requires RAM backup.

These ICs also support the backup mode of Renesas microcomputer the M16C.

Features

Bi-CMOS process realizes a configuration of low current dissipating circuits.
 Circuit current

 $I_{CC} = 3 \mu A$ (Typ, normal mode, $V_{CC} = 3.0 \text{ V}$) $I_{CC} = 1 \mu A$ (Typ, backup mode, $V_{CC} = 2.5 \text{ V}$)

Two-step detection of supply voltage

Detection voltage in normal mode: $V_S = 2.7 \text{ V (Typ)}$ Detection voltage in backup mode: $V_{BATT} = 2.0 \text{ V (Typ)}$

Two outputs

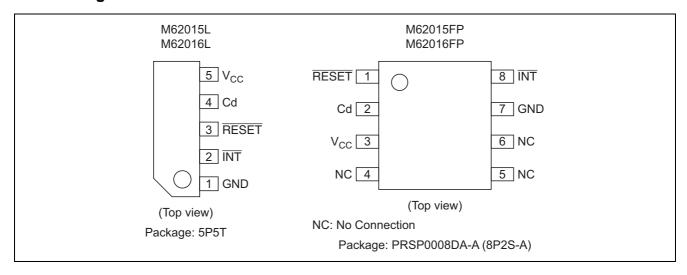
Reset output (RESET): output of compulsive reset signal Interruption output (INT): output of interruption signal

 Two types of output forms CMOS output: M62015L/FP open drain output: M62016L/FP

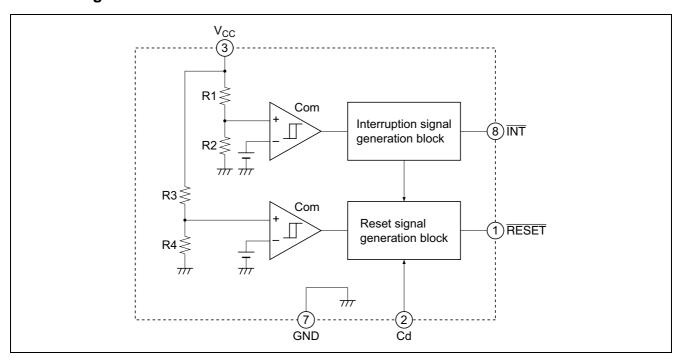
Application

• Prevention of errors in microcomputer system in electronic equipment that requires RAM backup, such as office, industrial, and home-use equipment.

Pin Arrangement



Block Diagram



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C, unless otherwise noted)$

Item	Symbol	Ratings	Unit	Conditions	
Supply voltage	V _{CC}	8	V		
Output sink current	Isink	4	mA		
Power dissipation	Pd	440	mW		
Thermal derating	Кθ	4.4	mW/°C	Ta ≥ 25°C	
Operating temperature	Topr	-20 to +75	°C		
Storage temperature	Tstg	-40 to +125	°C		

Electrical Characteristics

 $(Ta = 25^{\circ}C, unless otherwise noted)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Supply voltage	Vs	2.55	2.70	2.85	V	Interruption level during V _{CC} drop	
Battery voltage	V_{BATT}	1.85	2.00	2.15	V	Reset level at backup	
Hysteresis voltage	ΔV_S	_	60	1	mV	$\Delta V_S = V_{SH} - V_{SL}$	
Circuit current	I _{CC}	_	3.0	12	μΑ	V _{CC} = 3.0V: in normal mode	
		_	1.0	4.0		V _{CC} = 2.5V: in backup mode	
Sink ability	Vsat	_	0.4	0.6	V	V _{CC} = 2.5V, Isink = 2mA	
Delay time	td	_	50	_	ms	External capacitance Cd = 0.33μF	
Reset output response time	t _{RESET}	_	50		μS	When V _{CC} falling	
Interruption output reset time	t _{īNT}	_	40	_	μS	When V _{CC} falling	

Application Example

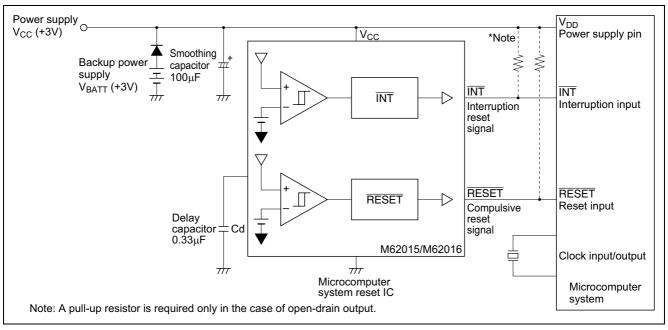
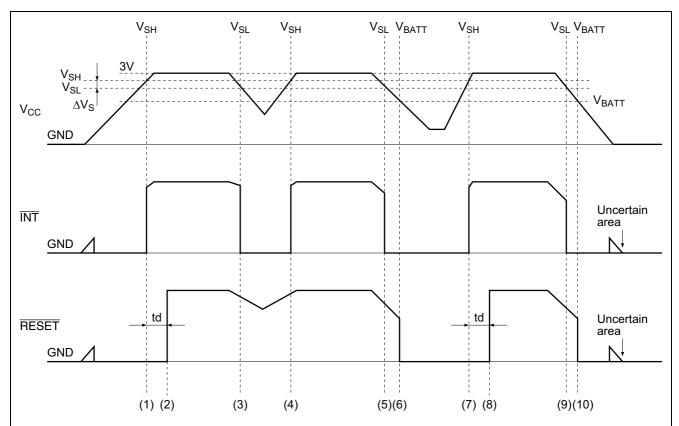


Figure 1 Application Example

Operating Description

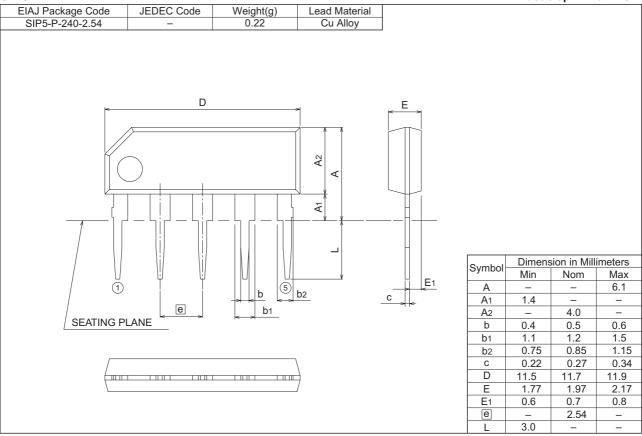


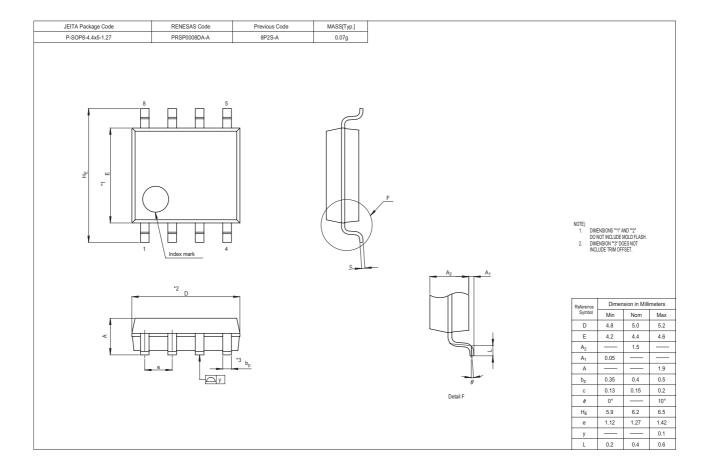
- (1): If V_{CC} rises to V_{SH} (2.76V), the \overline{INT} output is set to high level.
- (2): $\overline{\text{RESET}}$ goes high t_d (s) after V_{SH} .
 - * td = $1.52 \times 10^5 \times C$ (s)
- (3): If V_{CC} drops to V_{SL} (2.70V), \overline{INT} goes low.
 - * RESET output continues to be held high.
- (4): If V_{CC} returns to V_{SH} , the \overline{INT} output is set to high level.
- (5): Same as (3).
- (6): If V_{CC} becomes lower than V_{BATT} (2.00V), the RESET output is set to low thereby resetting the microcomputer and initializing system.
- (7): Same as (1).
- (8): Same as (2).
- (9): Same as (3) and (5).
- (10): Same as (6).

Figure 2 Operating Waveform

Package Dimensions

5P5T Plastic 5pin 240mil SIP





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Renesas Technology Singapore Pte. Ltd.

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Renesas Technology Korea Co., Ltd.Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> 2-796-3115, Fax: <82> 2-796-2145

Renesas Technology Malaysia Sdn. Bhd.

Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510